

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-60V	180mΩ@-10V	-1.8A
	200mΩ@-4.5V	

Feature

- High power and current handling capability
- Surface mount package

Application

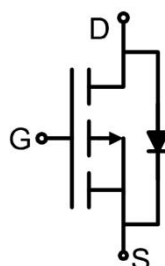
- Battery Switch
- DC/DC Converter

Package

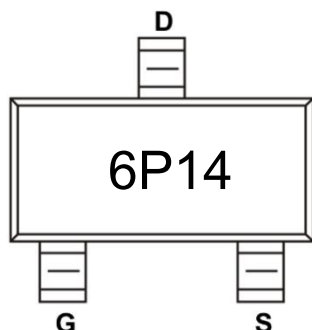


SOT-23

Circuit diagram



Marking



Absolute maximum ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-1.8	A
Pulsed Drain Current	I_{DM}	-7.2	A
Power Dissipation	P_D	1	W
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Operating Junction Temperature	T_J	$-55 \sim +150$	$^\circ\text{C}$
Storage Temperature	T_{STG}	$-55 \sim +150$	$^\circ\text{C}$

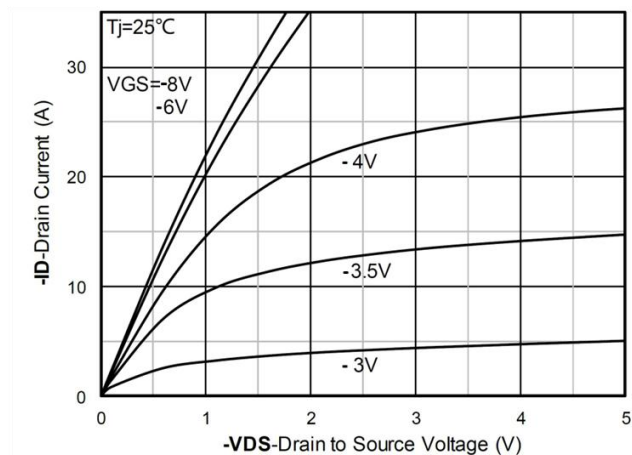
Electrical characteristics ($T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-60			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-48V, V _{GS} =0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.5	-2.5	V
Drain-source on-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-1.5A		140	180	mΩ
		V _{GS} =-4.5V, I _D =-1A		160	200	
Dynamic characteristics ¹⁾						
Input Capacitance	C _{iss}	V _{DS} =-30V, V _{GS} =0V, f =1MHz		455		pF
Output Capacitance	C _{oss}			28		
Reverse Transfer Capacitance	C _{rss}			19		
Total Gate Charge	Q _g	V _{DS} =-30V, V _{GS} =-10V I _D =-1.5A		9		nC
Gate-Source Charge	Q _{gs}			1.5		
Gate-Drain Charge	Q _{gd}			2		
Turn-on delay time	t _{d(on)}	V _{DS} =-30V, V _{GS} =-10V I _D =-1.5A, R _G =10Ω		40		nS
Turn-on rise time	t _r			36		
Turn-off delay time	t _{d(off)}			15		
Turn-off fall time	t _f			10		
Source-Drain Diode characteristics						
Diode Forward Current	I _S				-1.8	A
Diode Forward voltage	V _{SD}	V _{GS} =0V, I _S =-1A, T _J =25℃			-1.2	V

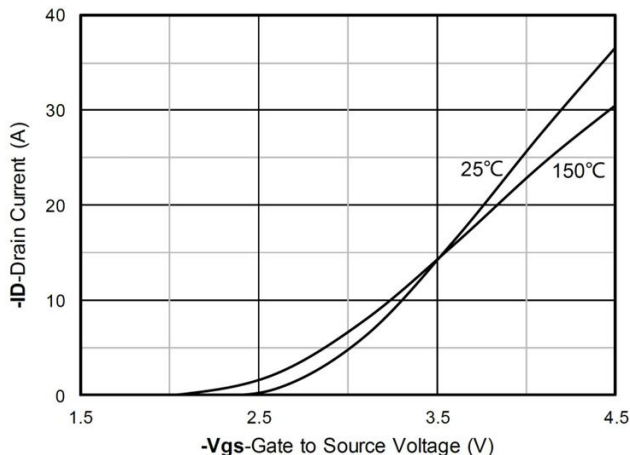
Notes:

1) Guaranteed by design, not subject to production testing.

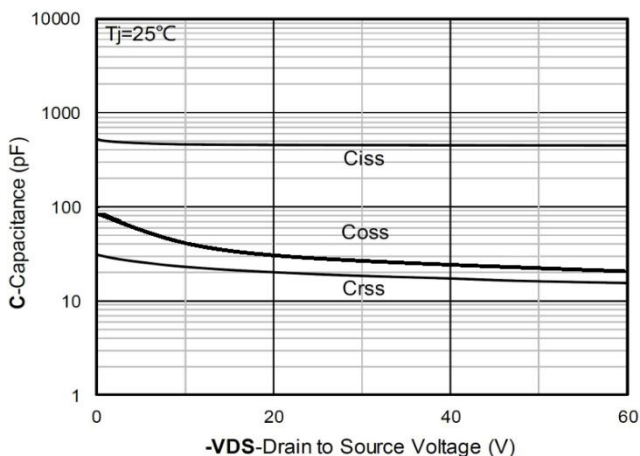
Typical Characteristics



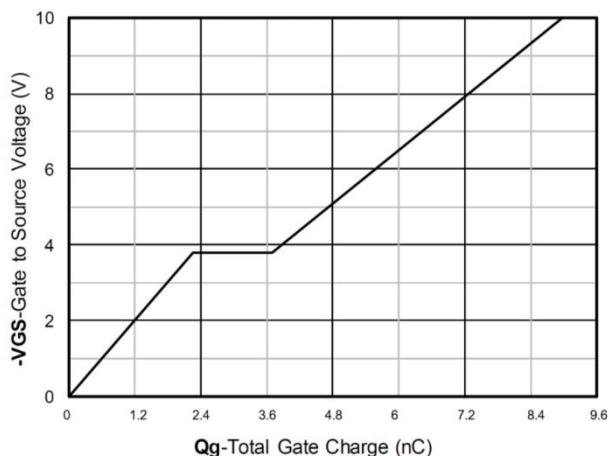
Output Characteristics



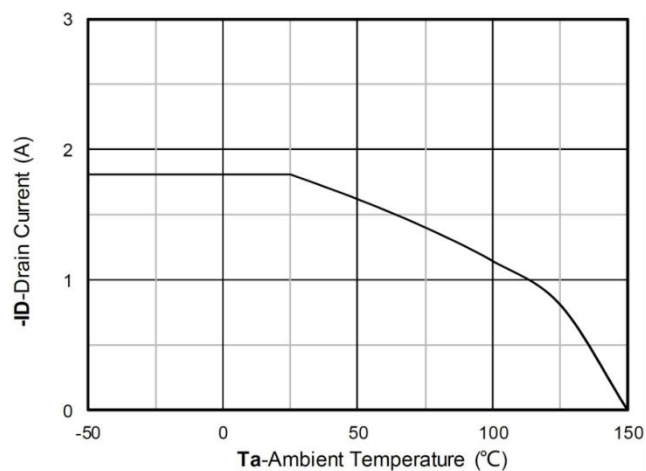
Transfer Characteristics



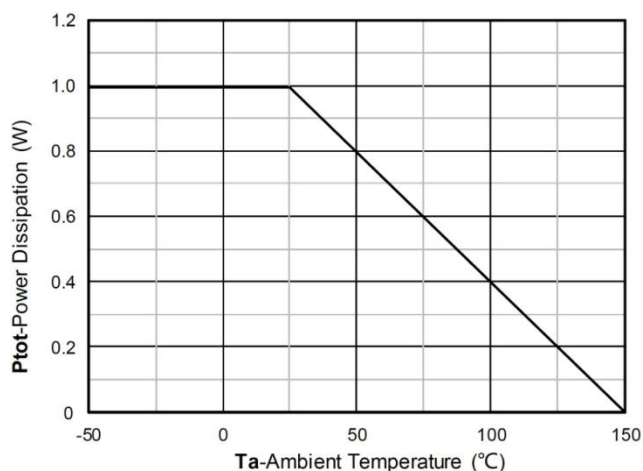
Capacitance Characteristics



Gate Charge

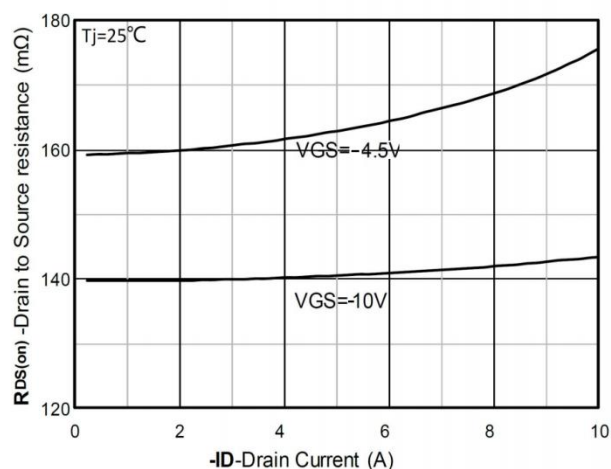


Current dissipation

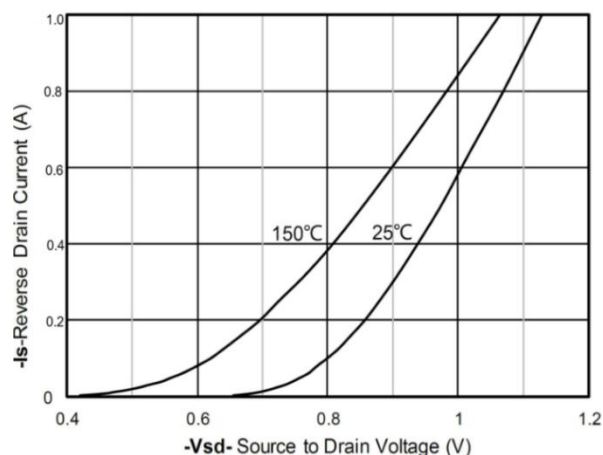


Power dissipation

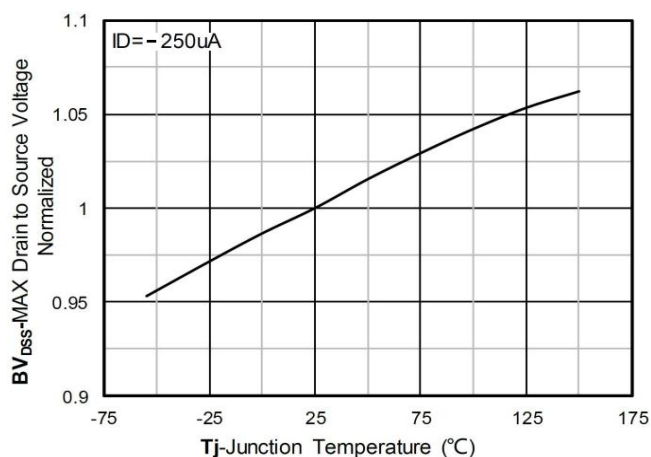
Typical Characteristics



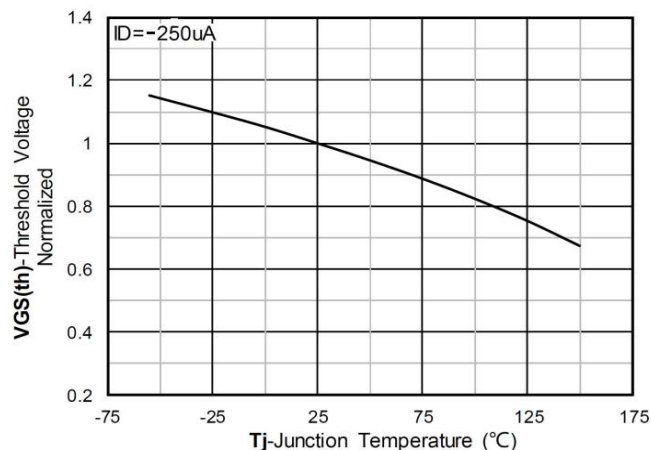
RDS(on) VS Drain Current



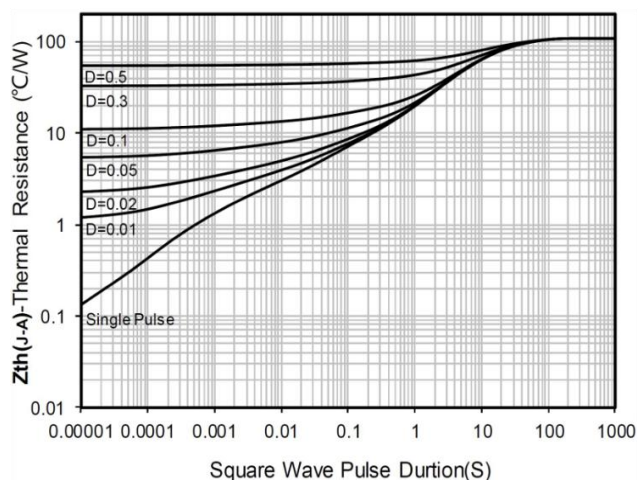
Forward characteristics of reverse diode



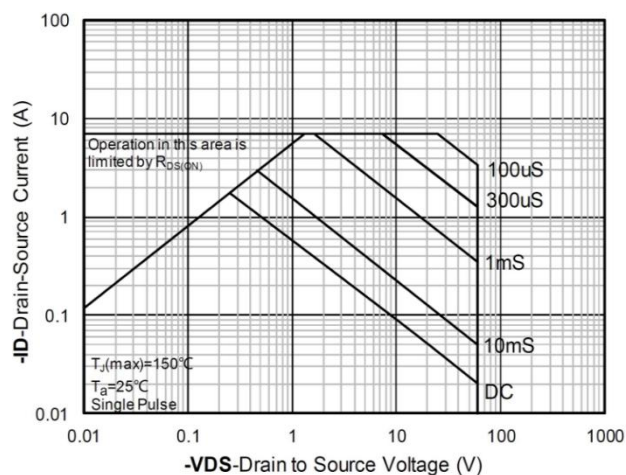
Normalized breakdown voltage



Normalized Threshold voltage

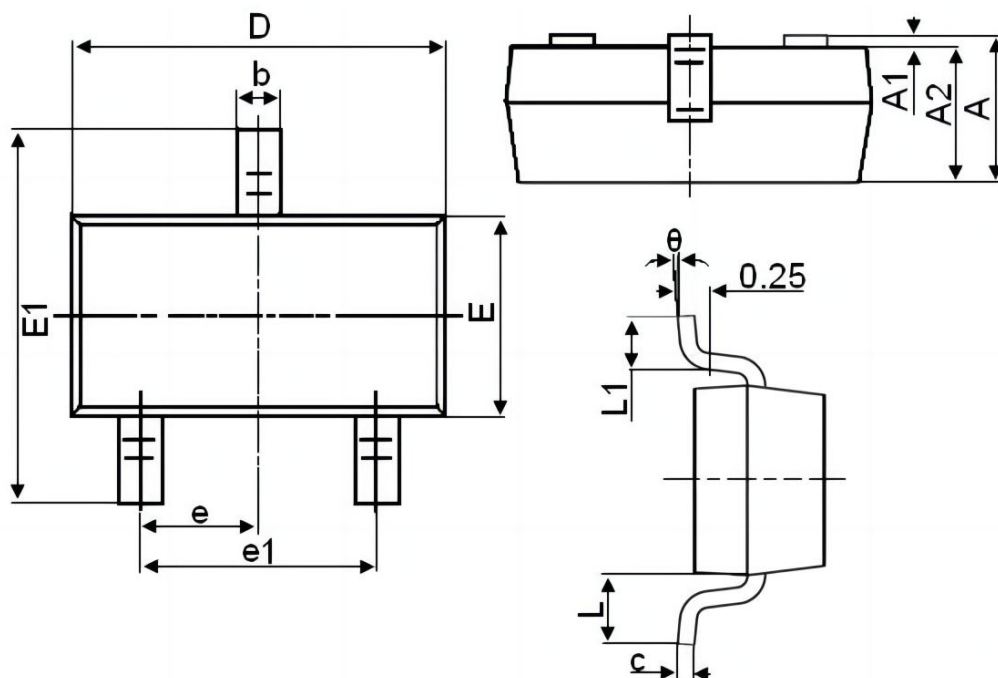


Maximum Transient Thermal Impedance



Safe Operation Area

SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°